

Pb Free Plating Product

MURF1220CTD/MURF1240CTD/MURF1260CTD



12.0 Ampere Insulated Dual Doubler Polarity Ultra Fast Recovery Rectifiers

<p>Features</p> <ul style="list-style-type: none"> ※ Fast switching for high efficiency ※ Low forward voltage drop ※ High current capability ※ Low reverse leakage current ※ High surge current capability <p>Application</p> <ul style="list-style-type: none"> ※ Automotive Inverters and Solar Inverters ※ Car Audio Amplifiers and Sound Device Systems ※ Plating Power Supply, Motor Control, UPS and SMPS etc. <p>Mechanical Data</p> <ul style="list-style-type: none"> ※ Case: Full Plastic Isolated Package ITO-220AB ※ Epoxy: UL 94V-0 rate flame retardant ※ Terminals: Solderable per MIL-STD-202 method 208 ※ Polarity: As marked on diode body ※ Mounting position: Any ※ Weight: 2.0 gram approximately 	<p>ITO-220AB(TO-220F-3L) Unit:inch(mm)</p> <p>Positive Common Cathode Suffix "CT"</p> <p>Negative Common Anode Suffix "CTR"</p> <p>Doubler Tandem Polarity Suffix "CTD"</p> <p>Series Tandem Polarity Suffix "CTS"</p>
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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	MURF1220CT MURF1220CTR MURF1220CTD MURF1220CTS	MURF1240CT MURF1240CTR MURF1240CTD MURF1240CTS	MURF1260CT MURF1260CTR MURF1260CTD MURF1260CTS	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	V
Maximum RMS Voltage	VRMS	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=100°C (Total Device 2x6.0A=12.0A)	IF(AV)	12.0			A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	100			A
Maximum Instantaneous Forward Voltage @6.0A (Per Diode/Per Leg)	VF	0.98	1.3	1.7	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	5.0 100			µA µA
Maximum Reverse Recovery Time (Note1)	Trr	35			nS
Typical Junction Capacitance (Note 2)	CJ	65			pF
Typical Thermal Resistance (Note 3)	RθJC	3.0			°C/W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 to +150			°C

Note:(1)Reverse recovery test conditions IF = 0.5A, IR = 1.0A, Irr = 0.25A.

Note:(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

Note:(3)Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

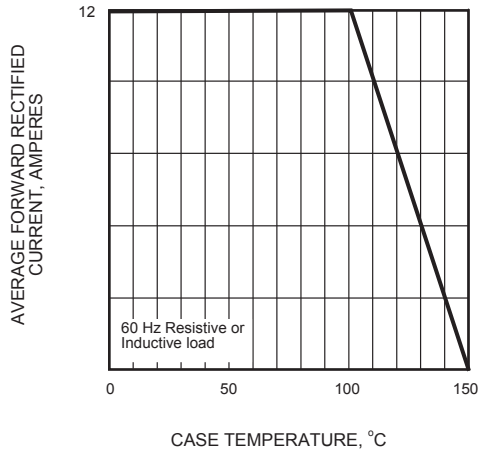


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

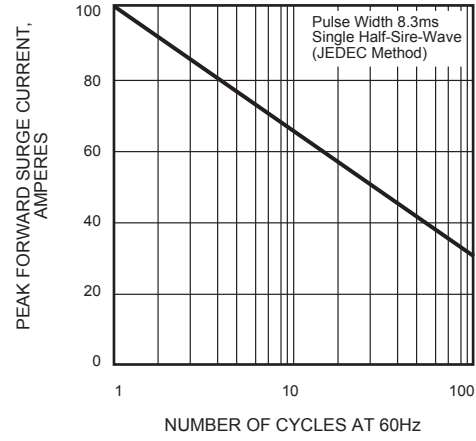


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

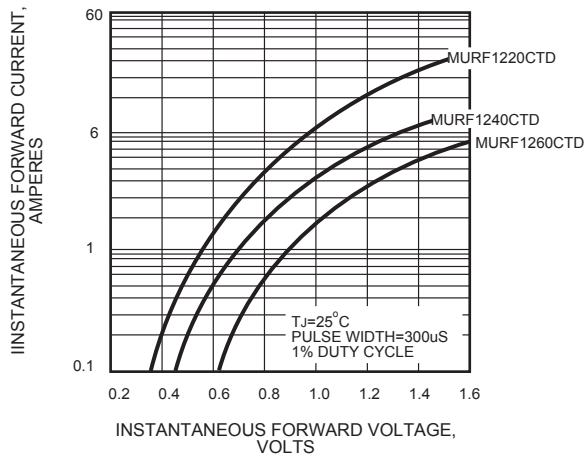


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

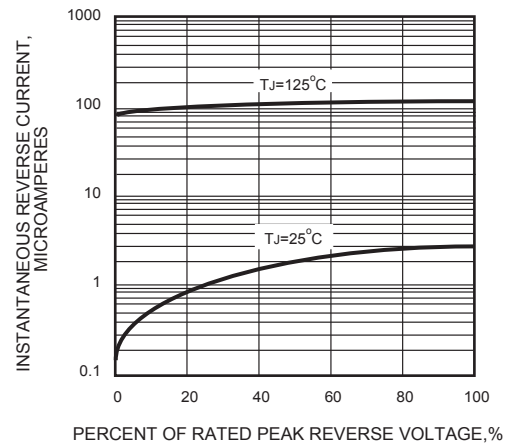


FIG.5 - TYPICAL JUNCTION CAPACITANCE

